BC635; BCP54; BCX54

45 V, 1 A NPN medium power transistors Rev. 07 — 4 June 2007

Product data sheet

Product profile

1.1 General description

NPN medium power transistor series.

Table 1. **Product overview**

Type number[1]	per[1] Package		PNP complement	
	NXP	JEITA	JEDEC	
BC635[2]	SOT54	SC-43A	TO-92	BC636
BCP54	SOT223	SC-73	-	BCP51
BCX54	SOT89	SC-62	TO-243	BCX51

^[1] Valid for all available selection groups.

1.2 Features

- High current
- Two current gain selections
- High power dissipation capability

1.3 Applications

- Linear voltage regulators
- Low side switches
- MOSFET drivers
- Amplifiers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	45	V
I _C	collector current		-	-	1	Α
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	1.5	Α
h _{FE}	DC current gain	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	63	-	250	
	h _{FE} selection -10	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	63	-	160	
	h _{FE} selection -16	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	100	-	250	



^[2] Also available in SOT54A and SOT54 variant packages (see Section 2).

2. Pinning information

Table 3.	Pinning	Cimplified autline	Cumbal
Pin	Description	Simplified outline	Symbol
SOT54	haaa		
1	base		2
2	collector		
3	emitter	001aab347	1 — sym056
SOT54A			
1	base		
2	collector		2
3	emitter	001aab348	1
SOT54 va	riant		
1	base		
2	collector		2
3	emitter	001aab447	1
SOT223			
1	base		
2	collector	4	2,
3	emitter		1 —
4	collector	1 2 3	3 sym016
SOT89			
1	emitter		
2	collector		:
3	base	3 2 1	3 — sym042

Ordering information 3.

Table 4. **Ordering information**

Type number[1]	Package					
	Name	Description	Version			
BC635 ^[2]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
BCP54	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			
BCX54	SC-62	plastic surface-mounted package; collector pad for good heat transfer; 3 leads	SOT89			

^[1] Valid for all available selection groups.

Marking 4.

Table 5. **Marking codes**

Type number	Marking code
BC635	C635
BC635-16	C63516
BCP54	BCP54
BCP54-10	BCP54/10
BCP54-16	BCP54/16
BCX54	ВА
BCX54-10	BC
BCX54-16	BD

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^[2] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

5. Limiting values

Table 6. Limiting values

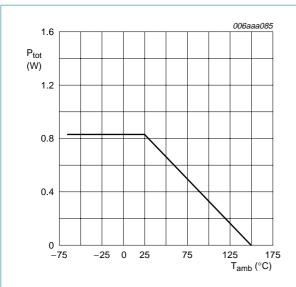
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	45	V
V_{CEO}	collector-emitter voltage	open base	-	45	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	1	Α
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	1.5	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	-	0.2	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	BC635		<u>[1]</u> -	0.83	W
	BCP54		<u>[1]</u> -	0.64	W
			[2] _	0.96	W
	BCX54		<u>[1]</u> -	0.5	W
			[2] _	0.85	W
			[3] _	1.25	W
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

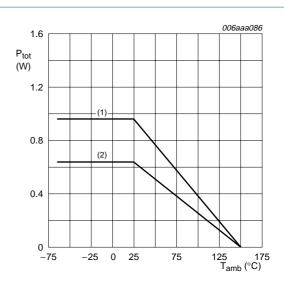
^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



FR4 PCB, standard footprint



(1) FR4 PCB, mounting pad for collector 1 cm²

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(2) FR4 PCB, standard footprint

Fig 2. Power derating curves SOT223

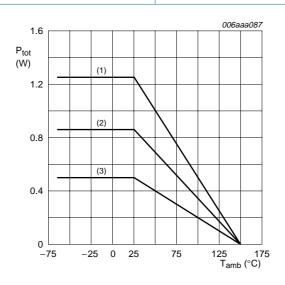


Fig 1. Power derating curve SOT54

- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 3. Power derating curves SOT89

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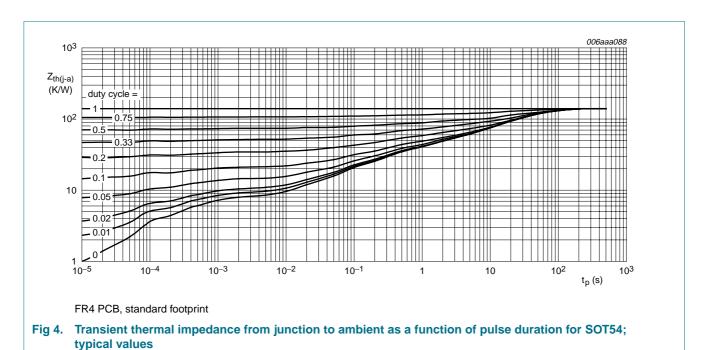
Product data sheet

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	in free air				
	BC635		<u>[1]</u> _	-	150	K/W
	BCP54		<u>[1]</u> _	-	195	K/W
			[2] _	-	130	K/W
	BCX54		<u>[1]</u> _	-	250	K/W
			[2] _	-	145	K/W
			[3]	-	100	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point					
	BC635		-	-	40	K/W
	BCP54		-	-	17	K/W
	BCX54		-	-	30	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



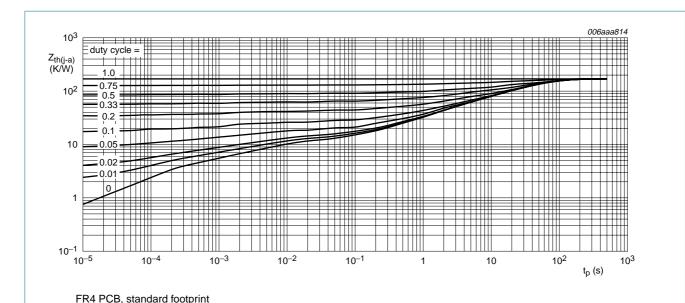


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values

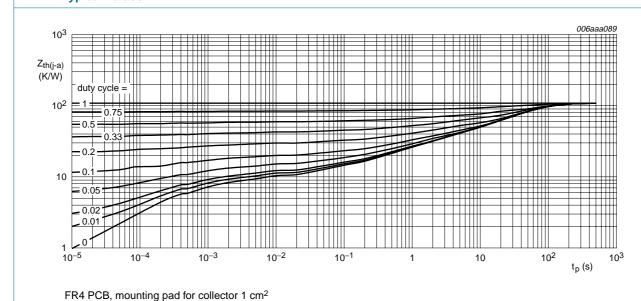


Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values

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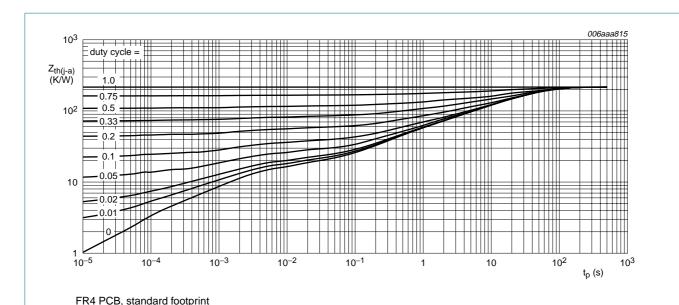
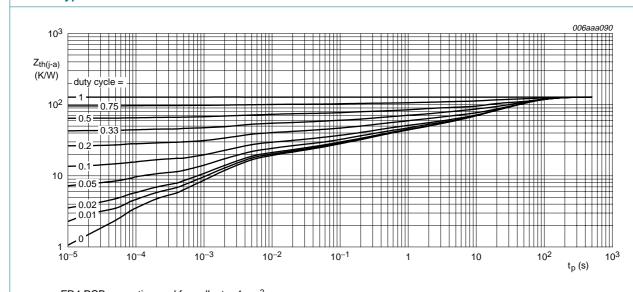


Fig 7. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

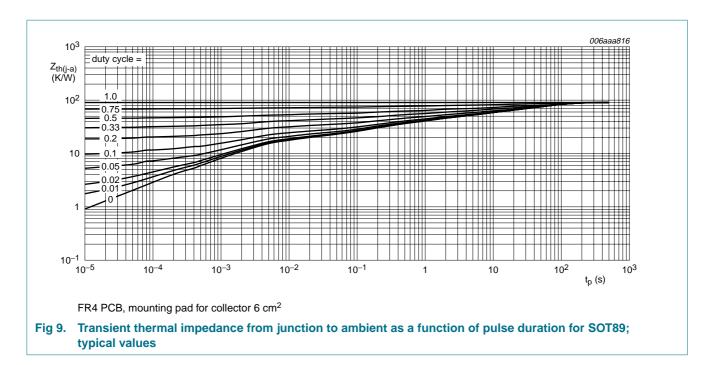


FR4 PCB, mounting pad for collector 1 cm²

Fig 8. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

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7. **Characteristics**

Characteristics

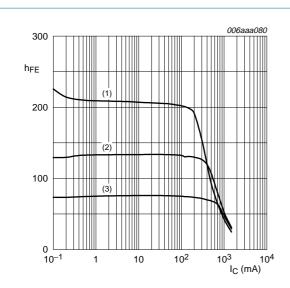
T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 2 V					
		$I_C = 5 \text{ mA}$		63	-	-	
		I _C = 150 mA		63	-	250	
		$I_C = 500 \text{ mA}$	<u>[1]</u>	40	-	-	
	DC current gain	$V_{CE} = 2 V$					
	h _{FE} selection -10	$I_C = 150 \text{ mA}$		63	-	160	
	h _{FE} selection -16	$I_C = 150 \text{ mA}$		100	-	250	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$	<u>[1]</u>	-	-	500	mV
V_{BE}	base-emitter voltage	$V_{CE} = 2 \text{ V}; I_{C} = 500 \text{ mA}$	<u>[1]</u>	-	-	1	V
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	6	-	pF
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA};$ f = 100 MHz		100	180	-	MHz

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta = 0.02$.

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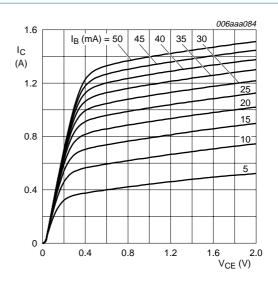
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$$V_{CE} = 2 V$$

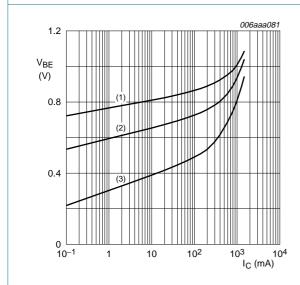
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 10. DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

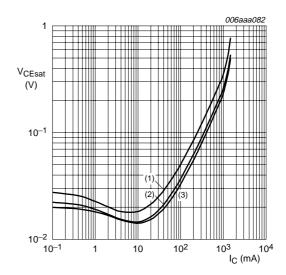
Fig 11. Collector current as a function of collector-emitter voltage; typical values





- (1) $T_{amb} = -55 \,^{\circ}C$
- (2) $T_{amb} = 25 \,^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

Fig 12. Base-emitter voltage as a function of collector current; typical values

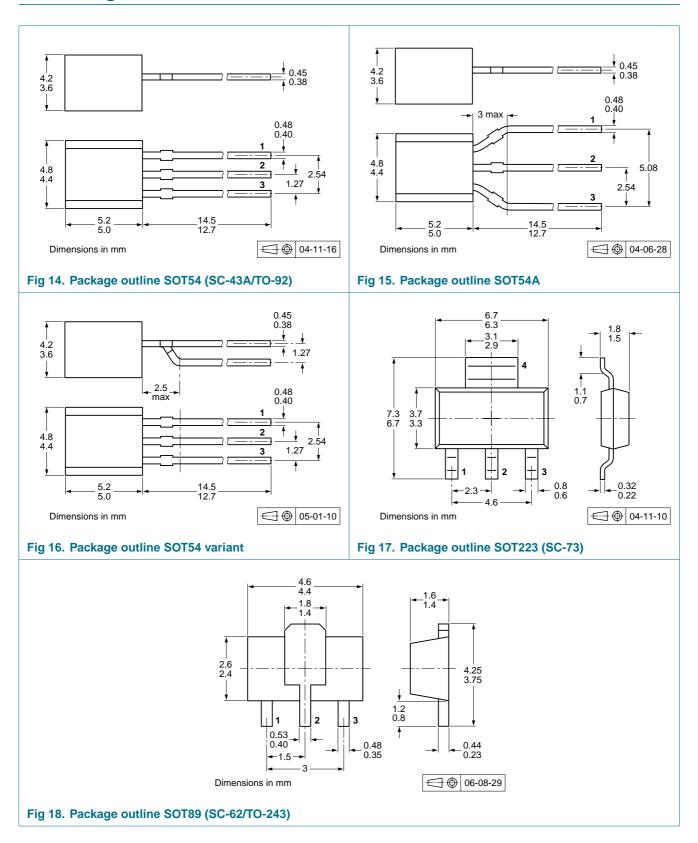


$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 13. Collector-emitter saturation voltage as a function of collector current; typical values

8. Package outline



9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number[2]	Package	Description	Packing	Packing quantity			
			1000	4000	5000	10000	
BC635	SOT54	bulk, straight leads	-	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-	-116	
		tape ammopack, wide pitch	-	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-	-112	-	
BCP54	SOT223	8 mm pitch, 12 mm tape and reel	-115	-135	-	-	
BCX54	SOT89	8 mm pitch, 12 mm tape and reel; T1	<u>3</u> -115	-135	-	-	
		8 mm pitch, 12 mm tape and reel; T3	<u>[4]</u> -120	-	-	-	

^[1] For further information and the availability of packing methods, see Section 12.

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^[2] Valid for all available selection groups.

^[3] T1: normal taping

^[4] T3: 90° rotated taping

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BC635_BCP54_BCX54_7	20070604	Product data sheet	-	BC635_BCP54_BCX54_6			
Modifications:	• Table 1 "Pro	oduct overview": amended					
	Section 1.2	"Features": amended					
	 Section 1.3 	"Applications": amended					
	 <u>Table 2 "Quick reference data"</u>: I_C parameter redefined to collector current 						
	Table 2 "Quick reference data": I _{CM} condition added						
	• Figure 2 and 3: amended						
	 Table 6 "Lin 	 <u>Table 6 "Limiting values"</u>: I_C parameter redefined to collector current 					
	 Table 6 "Lin 	niting values": I _{CM} condition	added				
	 Table 6 "Lin 	niting values": P _{tot} values fo	r BCP54 and BCX54	adapted			
	 <u>Table 7 "Thermal characteristics"</u>: R_{th(j-a)} values for BCP54 and BCX54 rounded 						
	 Figure 4: Z_{th} redefined to Z_{th(j-a)} transient thermal impedance from junction to ambient 						
	• Figure 4: t _p parameter redefined to pulse duration						
	• Figure 5: added						
	 Figure 6: Z_t 	$_{h}$ redefined to $Z_{th(j-a)}$ transie	ent thermal impedance	from junction to ambient			
	• Figure 6: t _p	parameter redefined to pul	se duration				
	• <u>Figure 7</u> : ad	dded					
	 Figure 8: Z_t 	$_{h}$ redefined to $Z_{th(j-a)}$ transic	ent thermal impedance	from junction to ambient			
	• Figure 8: t _p	parameter redefined to pul	se duration				
	• Figure 9: ad	dded					
	• <u>Figure 11</u> : a	amended					
	 <u>Table 9 "Packing methods"</u>: new packing method for BCX54 added 						
	• Section 11	"Legal information": update	d				
3C635_BCP54_BCX54_6	20050225	Product data sheet	CPCN200405029	BC635_637_639_4			
				BCP54_55_56_5			
20005 007 000 4	00044040	Dundant on a 'finati		BCX54_55_56_4			
3C635_637_639_4	20011010	Product specification	-	BC635_637_639_3			
BCP54_55_56_5	20030206	Product specification	-	BCP54_55_56_4			
BCX54_55_56_4	20011010	Product specification	-	BCX54_55_56_3			

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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